DATA SHEET



NPN SILICON RF TRANSISTOR NE664M04 / 2SC5754 JEITA Part No.

NPN SILICON RF TRANSISTOR FOR MEDIUM OUTPUT POWER AMPLIFICATION (0.4 W) FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04)

FEATURES

- · Ideal for 460 MHz to 2.4 GHz medium output power amplification
- Po(1 dB) = 26.0 dBm TYP. @ Vce = 3.6 V, f = 1.8 GHz, Pin = 15 dBm
- High collector efficiency: $\eta c = 60\%$
- UHS0-HV technology (f⊤ = 25 GHz) adopted
- · High reliability through use of gold electrodes
- Flat-lead 4-pin thin-type super minimold (M04) package

ORDERING INFORMATION

Part Number	Quantity	Supplying Form
NE664M04-A 2SC5754-A	50 pcs (Non reel)	8 mm wide embossed taping Pin 1 (Emitter), Pin 2 (Collector) face the perforation side of the tape
NE664M04-T2-A 2SC5754-T2-A	3 kpcs/reel	1 III 1 (Enlitter), 1 III 2 (Collector) lace the perioration side of the tape

Remark To order evaluation samples, contact your nearby sales office.

The unit sample quantity is 50 pcs.

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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ABSOLUTE MAXIMUM RATINGS ($T_A = +25$ °C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	13	V
Collector to Emitter Voltage	Vceo	5.0	٧
Emitter to Base Voltage	VEBO	1.5	٧
Collector Current	lc	500	mA
Total Power Dissipation	Ptot Note	735	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-65 to +150	°C

Note Mounted on 38×38 mm, t = 0.4 mm polyimide PCB

THERMAL RESISTANCE

Parameter	Symbol	Test Conditions	Ratings	Unit
Junction to Ambient Resistance	Rth j-a1	Mounted on 38 × 38 mm, t = 0.4 mm polyimide PCB	170	°C/W
	Rth j-a2	Stand alone device in free air	570	°C/W

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
OC Characteristics						
Collector Cut-off Current	Ісво	Vcb = 5 V, IE = 0 mA	-	-	1 000	nA
Emitter Cut-off Current	ІЕВО	VBE = 1 V, Ic = 0 mA	-	-	1 000	nA
DC Current Gain	hfE Note 1	Vce = 3 V, Ic = 100 mA	40	60	100	-
RF Characteristics						
Gain Bandwidth Product	f⊤	Vce = 3 V, Ic = 100 mA, f = 0.5 GHz	16	20	-	GHz
Insertion Power Gain	S _{21e} ²	Vce = 3 V, Ic = 100 mA, f = 2 GHz	5.0	6.5	_	dB
Reverse Transfer Capacitance	Cre Note 2	VcB = 3 V, IE = 0 mA, f = 1 MHz	-	1.0	1.5	pF
Maximum Available Power Gain	MAG Note 3	Vce = 3 V, Ic = 100 mA, f = 2 GHz	-	12.0	-	dB
Linear Gain	G∟	$V_{CE} = 3.6 \text{ V}, I_{Cq} = 20 \text{ mA}, f = 1.8 \text{ GHz},$ $P_{in} = 0 \text{ dBm}, 1/2 \text{ Duty}$	-	12.0	-	dB
Gain 1 dB Compression Output Power	Po (1 dB)	$V_{CE} = 3.6 \text{ V}, I_{Cq} = 4 \text{ mA}, f = 1.8 \text{ GHz}, P_{in} = 15 \text{ dBm}, 1/2 \text{ Duty}$	-	26.0	-	dBm
Collector Efficiency	ης	V _{CE} = 3.6 V, I _{Cq} = 4 mA, f = 1.8 GHz, P _{in} = 15 dBm, 1/2 Duty	-	60	-	%

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

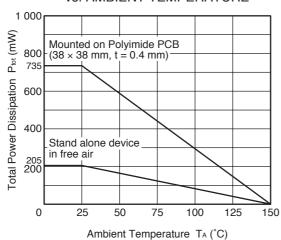
3. MAG =
$$\left| \frac{S_{21}}{S_{12}} \right| (K - \sqrt{(K^2 - 1)})$$

hfe CLASSIFICATION

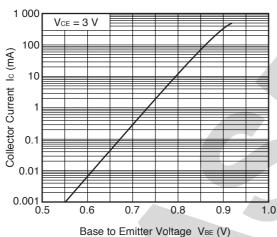
Rank	FB
Marking	R57
hre Value	40 to 100

TYPICAL CHARACTERISTICS (Unless otherwise specified, TA = +25°C)

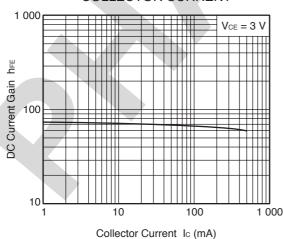
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



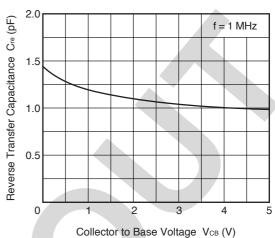
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



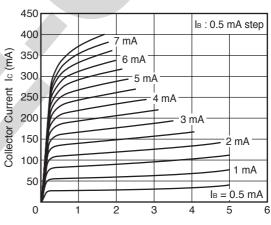
DC CURRENT GAIN vs. COLLECTOR CURRENT



REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

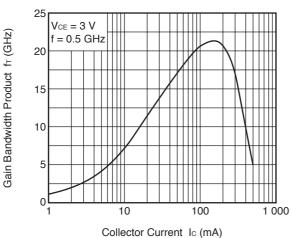


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

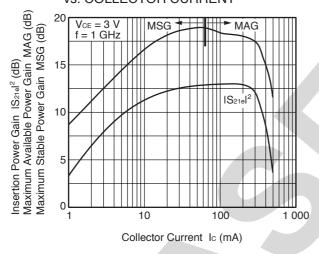


Collector to Emitter Voltage VcE (V)

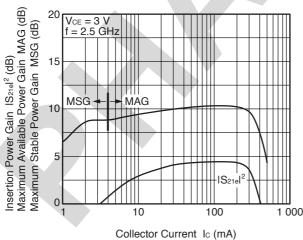
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



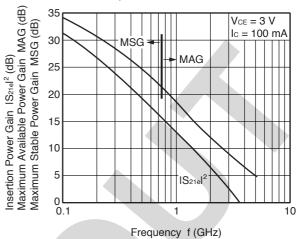
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



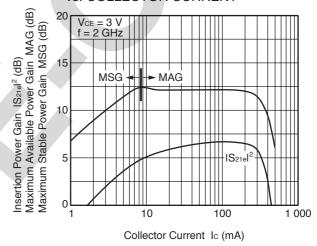
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

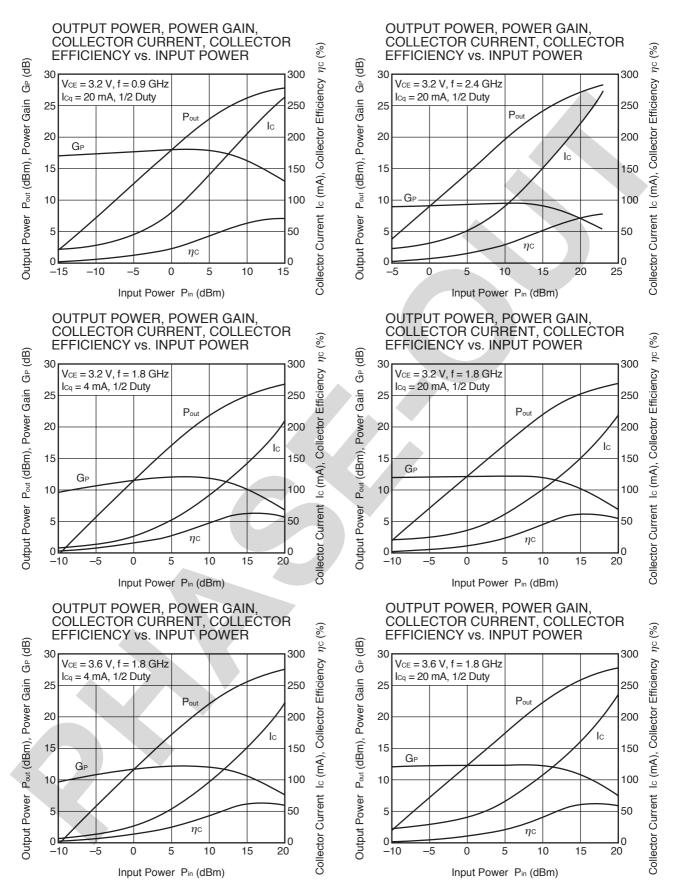


INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



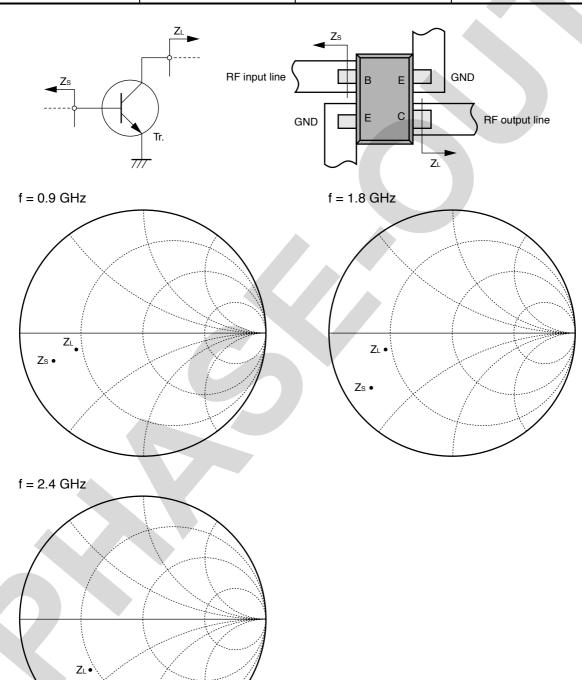


Remark The graphs indicate nominal characteristics.

Zs•

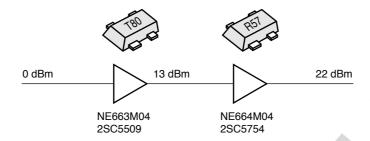
POWER SUPPLY IMPEDANCE, LOAD IMPEDANCE (Recommended value)

Frequency f (GHz)	Collector to Emitter Voltage VCE (V)	Supply Impedance $Z_{\mathbb{S}}\left(\Omega ight)$	Load Impedance $Z_L\left(\Omega ight)$
0.9	2.8 to 3.6	8.4 – 5.2 j	15.1 – 4.3 j
1.8	2.8 to 3.6	6.3 – 16.4 j	15.8 – 6.9 j
2.4	2.8 to 3.6	5.9 – 22.1 j	15.2 – 17.9 j

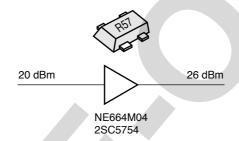


APPLICATION EXAMPLE (Low-cost PA solution)

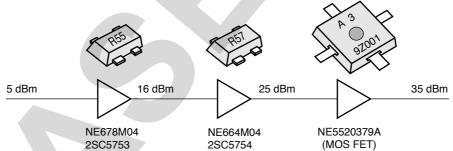
Bluetooth Power Class 1 f = 2.4 GHz



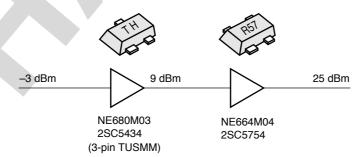
SS Cordless Phone f = 2.4 GHz



DCS1800 (GSM1800) Cellular Phone f = 1.8 GHz

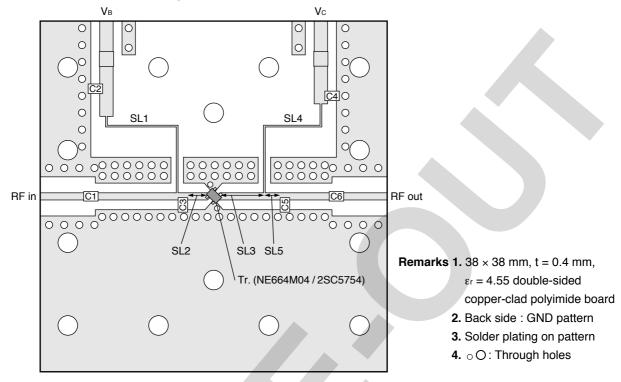


Cordless Phone f = 0.9 GHz

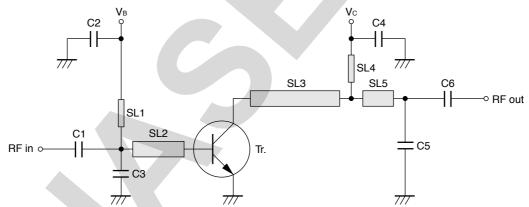


EVALUATION CIRCUIT EXAMPLE: 1.8 GHz PA EVALUATION BOARD

PCB Pattern and Element Layout



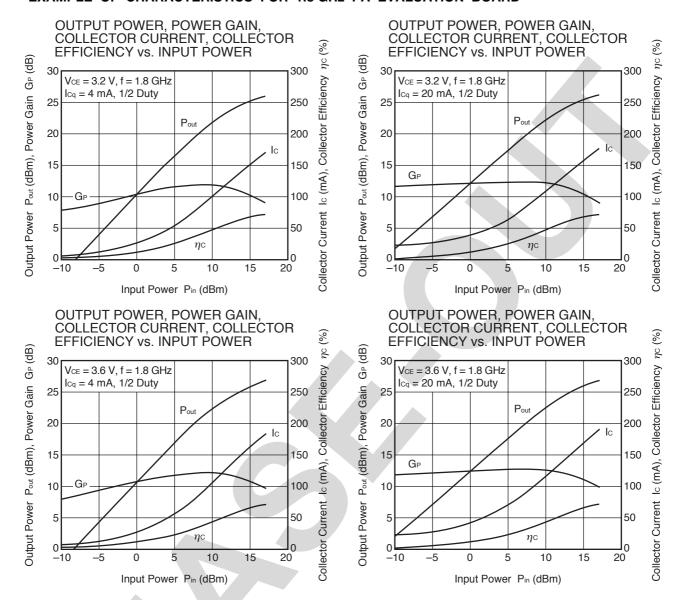
Equivalent Circuit



Parts List

Parts	Value	Size	Classification
C1, C6	18 pF		Multiplayer ceramic chip capacitor
C2	3 300 pF		Multiplayer ceramic chip capacitor
С3	3 pF		Multiplayer ceramic chip capacitor
C4	15 pF		Multiplayer ceramic chip capacitor
C5	1.5 pF		Multiplayer ceramic chip capacitor
SL1, SL4		w = 0.20 mm	Strip line
SL2		w = 0.76 mm, I = 2.5 mm	Strip line
SL3		w = 0.76 mm, I = 5 mm	Strip line
SL5		w = 0.76 mm, I = 1.5 mm	Strip line

EXAMPLE OF CHARACTERISTICS FOR 1.8 GHz PA EVALUATION BOARD



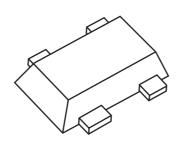
Remark The graphs indicate nominal characteristics.

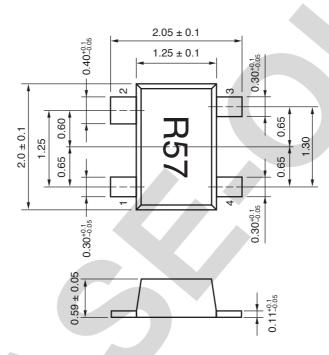
S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/

PACKAGE DIMENSIONS

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)





PIN CONNECTIONS

- 1. Emitter
- 2. Collector
- 3. Emitter
- 4. Base

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